





SOT-23 Formed SMD Package

CMBT5400

HIGH VOLTAGE TRANSISTOR

P-N-P transistor

Marking CMBT5400 = K2

PACKAGE OUTLINE DETAILS
ALL DIMENSIONS IN mm

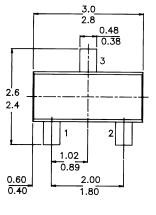


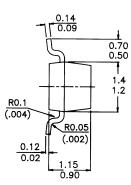
1 = BASE

2 = EMITTER

3 = COLLECTOR







ABSOLUTE MAXIMUM RATINGS

Collector-base voltage (open emitter)	$-V_{CBO}$	max.	130	V
Collector-emitter voltage (open base)	$-V_{CEO}$	max.	120	V
Emitter-base voltage (open collector)	$-V_{EBO}$	max.	5	V
Collector current (d.c.)	$-I_C$	max.	<i>500</i>	mA
Total power dissipation at $T_{amb} = 25^{\circ}C$	P_{tot}	max	<i>250</i>	mW
D.C. current gain				
$-I_C = 10 \text{ mA; } -V_{CF} = 5 \text{ V}$	h_{FE}	min.	40	
1(- 10 mm, VCE - 0 V	"FE	max.	180	

RATINGS (at $T_A = 25^{\circ}C$ unless otherwise specified)

Limiting values

Collector-base voltage (open emitter)	$-V_{CBO}$	max.	130	V
Collector-emitter voltage (open base)	$-V_{CEO}$	max.	120	V
Emitter-base voltage (open collector)	$-V_{EBO}$	max.	5	V
Collector current (d.c.)	$-I_{C}$	may	500	$m\Delta$

Total power dissipation at $T_{amb} = 25^{\circ}C$	P_{tot}	max	250	mW
Storage temperature	T_{Stg}	−55 to	+150	$^{\circ}$ C
Junction temperature	Tj	max.	150	°C
THERMAL CHARACTERISTICS				
$T_i = P (R_{th j-t} + R_{th s-a}) + T_{amb}$				
Thermal resistance				
from junction to ambient	$R_{th\ j-a}$		200	°C/mW
CHARACTERISTICS (at $T_A = 25^{\circ}C$ unless otherw	vise specified)			
Collector-emitter breakdown voltage				
$-I_C = 1 \text{ mA}; I_B = 0$	−V _(BR) CE	o min.	120	V
Collector-base breakdown voltage	, ,			
$-I_C = 100 \ \mu A; I_E = 0$	$-V_{(BR)CBC}$	o min.	130	V
Emitter-base breakdown voltage				
$-I_E = 10 \ \mu A; I_C = 0$	$-V_{(BR)EBO}$	o min.	5	V
Collector cut-off current				
$-V_{CB} = 100 \ V; I_E = 0 \ V$	$-I_{CBO}$	max.	100	nΑ
Emitter cut-off current				
$-V_{EB} = 3V$; $I_C = 0$	$-I_{EBO}$	max.	<i>50</i>	nA
Output capacitance at $f = 1$ MHz				
$I_E = 0$; $-V_{CB} = 10 \text{ V}$	C_c	max.	6	pF
Saturation voltages				
$-I_C = 10 \text{ mA}; -I_B = 1 \text{ mA}$	-V _{CEsat}	max.	0.2	V
	-V _{BEsat}	max.	1	V
$-I_C = 50$ mA; $-I_B = 5$ mA	-V _{CEsat}	max.	0.5	V
$-I_C = 50 \text{ mA}; -I_B = 5 \text{ mA}$	-V _{BEsat}	max.	1	V
D.C. current gain				
$-I_C = 1 \text{ mA; } -V_{CE} = 5 \text{ V}$	h_{FE}	min.	50	
$-I_C = 10 \text{ mA; } -V_{CF} = 5 \text{ V}$	$h_{\!F\!E}$	min.	40	
6 62	12	max.	180	
$-I_C = 50 \text{ mA; } -V_{CE} = 5 \text{ V}$	hee	min.	40	
$-1C = 30 \text{ mA}, -v_{CE} = 3 \text{ V}$ Noise figure at $R_S = 1 \text{ k}\Omega$	h_{FE}	111111.	40	
Noise figure at $KS = 1 \text{ K}2$ $-I_C = 200 \mu\text{A}; -V_{CE} = 5 V$				
f = 10 Hz to 15.7 kHz	NF	max.	8	dВ
1 - 10 112 to 10.7 M12	1 41	man.	U	uD

Customer Notes

Disclaimer

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